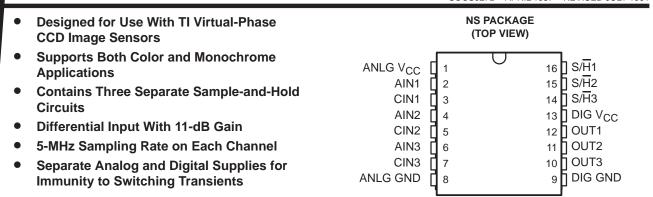
TL1593C 3-CHANNEL SAMPLE-AND-HOLD CIRCUIT

SOCS027B - APRIL 1987 - REVISED JULY 1991



description

The TL1593C is a three-channel sample-and-hold integrated circuit designed for use in processing video signals generated by TI virtual-phase CCD image sensors. It can be used with one-, two-, and three-channel color and monochrome TI virtual-phase CCDs.

Each sample-and-hold channel consists of a differential-input buffer, a digitally controlled switch, and an output buffer that has high impedance. Separate supply and ground pins are provided for the analog and digital sections to ensure optimum isolation. Internal-hold capacitors are included to reduce the external parts count. The differential inputs allow the amplifier return pin of the imager to be connected to CIN of the sample-and-hold circuit to obtain common-mode rejection for antiblooming clock transients in the CCD. The analog inputs should be capacitively coupled from the CCD outputs to ensure optimum performance.

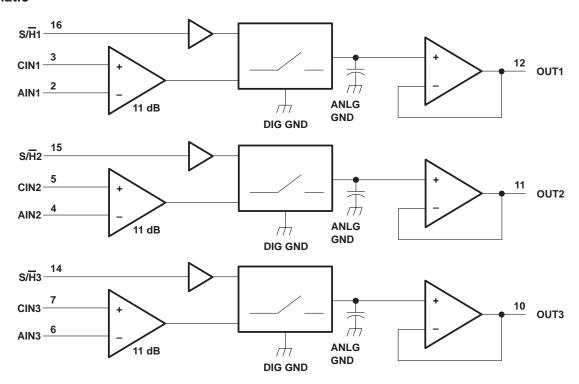
The TL1593C is supplied in a 16-pin plastic package and is characterized for operation from 0°C to 70°C.

This device contains circuits to protect its inputs and outputs against damage due to high static voltages or electrostatic fields. These circuits have been qualified to protect this device against electrostatic discharges (ESD) of up to 2 kV according to MIL-STD-883C, Method 3015; however, precautions should be taken to avoid application of any voltage higher than maximum-rated voltages to these high-impedance circuits. During storage or handling, the device leads should be shorted together or the device should be placed in conductive foam. In a circuit, unused inputs should always be connected to an appropriate logic voltage level, preferably either VCC or ground.

conductive foam. In a circuit, unused inputs should always be connected to an appropriate logic voltage level, preferably either V_{CC} or ground. Specific guidelines for handling devices of this type are contained in the publication *Guidelines for Handling Electrostatic-Discharge-Sensitive (ESDS) Devices and Assemblies* available from Texas Instruments.



schematic



Terminal Functions

TERMINAL		1/0	DESCRIPTION		
NAME	NO.	1/0	DESCRIPTION		
AIN1	2	I	Channel 1 analog input		
AIN2	4	I	Channel 2 analog input		
AIN3	6	I	Channel 3 analog input		
ANLG GND	8		Analog ground		
ANLG V _{CC}	1		Analog supply voltage		
CIN1	3	I	Channel 1 compensation input		
CIN2	5	I	Channel 2 compensation input		
CIN3	7	I	Channel 3 compensation input		
DIG GND	9		Digital ground		
DIG V _{CC}	13		Digital supply voltage		
OUT1	12	0	Channel 1 output		
OUT2	11	0	Channel 2 output		
OUT3	10	0	Channel 3 output		
S/H1	16	I	Channel 1 sample-and-hold input		
S/H2	15	I	Channel 2 sample-and-hold input		
S/H3	14	I	Channel 3 sample-and-hold input		



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Analog supply voltage range, ANLG V _{CC} (see Note 1)	0.4 V to 16 V
Digital supply voltage range, DIG V _{CC}	0.4 V to 16 V
Input voltage range, V _I : AINn inputs	$\dots \dots $
CINn inputs	-0.4 V to ANLG V _{CC}
S/Hn inputs	0.4 V to DIG V _{CC}
Continuous total power dissipation at (or below) T _A ≤ 25°C	625 mW
Operating free-air temperature range, T _A	30°C to 75°C
Storage temperature range, T _{STG}	–55°C to 125°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to GND.

recommended operating conditions

		MIN	NOM	MAX	UNIT	
Analog supply voltage, ANLG V _{CC}		10	12	13	V	
Digital supply voltage, DIG V _{CC}		10	12	13	V	
High-level input voltage, VIH		2			V	
Low-level input voltage, V _{IL}				0.8	V	
Input bias voltage, VIR	AINn inputs	4.9	5.1	5.3		
Imput bias voitage, VIB	CINn inputs	2.2	2.4	2.6		
Input voltage V	AINn inputs	V _{IB} – 0.3	V _{IB}	V _{IB} + 0.3	V	
Input voltage, V _I	CINn inputs	V _{IB} – 0.2	V _{IB}	V _{IB} + 0.2	V	
Sampling frequency				5	MHz	
Sampling time		55			ns	
Operating free-air temperature, TA		30		75	°C	

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER		TEST C	TEST CONDITIONS		TYP‡	MAX	UNIT
	Output voltage level				6	6.75	7.5	V
	Output voltage swing				2			V
lіН	High-level input current		V _I = 2.7 V,	DIG V _{CC} = 12 V			10	μΑ
IIL	Low-level input current		V _I = 0.4 V,	DIG V _{CC} = 12 V		-160	-300	μΑ
lo_	Output source current				-5			mA
I _{O+}	Output sink current				0.4			mA
Icc	Supply current		DIG V _{CC} = 12 V,	ANLG V _{CC} = 12 V		18.5	28	mA
Ci	Input capacitance	AINn inputs				5	7	pF
		CINn inputs				19	24	
		S/Hn inputs				13	18	
	Input impedance	AINn inputs				100		kΩ
Output impedance						50	200	Ω

 $[\]ddagger$ All typical values are at $T_A = 25^{\circ}$ C.



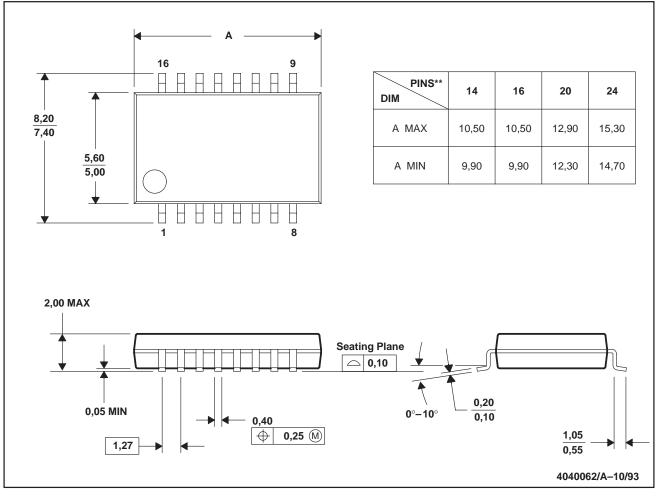
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MECHANICAL DATA

NS/R-PDSO-G**

16 PIN SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

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